NSN 5961-01-365-5029

Demilitarization:

No Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-365-5029 **Inclosure Material:** Metal **Overall Length:** Between 0.645 inches and 0.675 inches **Terminal Length:** 0.180 inches **Overall Height:** 0.210 inches **Overall Width:** 0.415 inches **Mounting Facility Quantity: Internal Configuration:** Field effect **Mounting Method:** Unthreaded hole **Features Provided:** Burn in and electrostatic sensitive and hermetically sealed case and w/heat sink **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 500.0 drain to source voltage **Current Rating Per Characteristic:** 4.40 amperes drain current **Power Rating Per Characteristic:** 50.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 80.0 degrees celsius junction **Test Data Document:** 28527-3131516 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**